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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
09/928,194	08/11/2001	Kurt E. Petersen	356952000304	8004
7	590 04/04/2005		EXAMINER	
Stephen C. Durant			KANG, DONGHEE	
Morrison & Foerster LLP 425 Market Street		ART UNIT	PAPER NUMBER	
San Francisco, CA 94105-2482			2811	
			DATE MAILED: 04/04/2005	5

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
		PETERSEN ET AL.	M		
Office Action Summary	09/928,194				
	Examiner	Art Unit			
The MAIL INC DATE of this communication and	Donghee Kang	2811			
The MAILING DATE of this communication app Period for Reply	ears on the cover sneet with the c	orrespondence address -	-		
A SHORTENED STATUTORY PERIOD FOR REPLY THE MAILING DATE OF THIS COMMUNICATION.  - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a reply - If NO period for reply is specified above, the maximum statutory period who is aliure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	66(a). In no event, however, may a reply be time within the statutory minimum of thirty (30) days ill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communica D (35 U.S.C. § 133).	ition.		
Status					
1) Responsive to communication(s) filed on 24 Ja	nuary 200 <u>5</u> .				
a) ☐ This action is <b>FINAL</b> . 2b) ☑ This action is non-final.					
3) Since this application is in condition for allowar	nce except for formal matters, pro	secution as to the merits	s is		
closed in accordance with the practice under E	x parte Quayle, 1935 C.D. 11, 45	53 O.G. 213.			
Disposition of Claims					
4) Claim(s) <u>58-89</u> is/are pending in the application	1.				
4a) Of the above claim(s) is/are withdraw					
5) Claim(s) is/are allowed.					
6)⊠ Claim(s) <u>58-89</u> is/are rejected.					
7) Claim(s) is/are objected to.					
8) Claim(s) are subject to restriction and/or	r election requirement.				
Application Papers					
9) The specification is objected to by the Examine	r.				
10) ☐ The drawing(s) filed on is/are: a) ☐ acce	epted or b) $\square$ objected to by the I	Examiner.			
Applicant may not request that any objection to the	drawing(s) be held in abeyance. See	e 37 CFR 1.85(a).			
Replacement drawing sheet(s) including the correct					
11)☐ The oath or declaration is objected to by the Ex	aminer. Note the attached Office	Action or form PTO-152	<b>!</b>		
Priority under 35 U.S.C. § 119					
<ul> <li>12) Acknowledgment is made of a claim for foreign</li> <li>a) All b) Some * c) None of:</li> <li>1. Certified copies of the priority documents</li> <li>2. Certified copies of the priority documents</li> <li>3. Copies of the certified copies of the priority application from the International Bureau</li> <li>* See the attached detailed Office action for a list</li> </ul>	s have been received. s have been received in Applicati rity documents have been receive u (PCT Rule 17.2(a)).	ion No ed in this National Stage			
Attachment/c)					
Attachment(s)  1) Notice of References Cited (PTO-892)	4) 🔲 Interview Summary	(PTO-413)			
2) Notice of Draftsperson's Patent Drawing Review (PTO-948)  3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	Paper No(s)/Mail D				
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#### **DETAILED ACTION**

### Claim Rejections - 35 USC § 112

1. The following is a quotation of the first paragraph of 35 U.S.C. 112:

The specification shall contain a written description of the invention, and of the manner and process of making and using it, in such full, clear, concise, and exact terms as to enable any person skilled in the art to which it pertains, or with which it is most nearly connected, to make and use the same and shall set forth the best mode contemplated by the inventor of carrying out his invention.

2. Claims 58-89 are rejected under 35 U.S.C. 112, first paragraph, as failing to comply with the written description requirement. The claim(s) contains subject matter which was not described in the specification in such a way as to reasonably convey to one skilled in the relevant art that the inventor(s), at the time the application was filed, had possession of the claimed invention.

Re claims 55, 70, 74 & 83, the phrase "a single crystal silicon structure.... including two oppositely disposed substantially vertical major surfaces and including two oppositely disposed generally horizontal minor surfaces wherein the aspect ratio of major surface to minor surface is at least 5:1" is not supported by the specification.

Claims 56-69, 71-73, 75-82 & 84-89 are rejected because each includes the limitations of independent claims 55, 70, 74 & 83.

## Response to Arguments

3. Applicant's arguments filed 01-24-05 have been fully considered but they are not persuasive.

"Summary of the invention" describes the embodiment as described in Fig.1 which is issued as U.S.Patent No. 6,316,796. The Fig.9 does not show that single

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crystal structure is formed in the first wafer layer and a carrier, which includes a recessed region is secured to the first wafer layer such that said structure is suspended opposite the recessed region.

The "aspect ratios of up to 20:1" means the holes or trenches (page 17, lines 17-20) but not single crystal silicon structure. The specification describes the ratio is between the depth of the etched region and the width of the etched region. Thus, the ration 20:1 does not mean the ratio of major surface to minor surface.

Fig.9 shows a suspended structure 218 surrounded by such high aspect ration channel 216. the channel 218, which has a high aspect ratio, is made using DRIE process used in Fig.8.

#### Conclusion

4. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Donghee Kang whose telephone number is 571-272-1656. The examiner can normally be reached on Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie C. Lee can be reached on 571-272-1732. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306. Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For

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more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Donghee Kang Primary Examiner Art Unit 2811

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